

Title (en)

SOLAR CELL AND SOLAR-CELL MODULE

Title (de)

SOLARZELLE UND SOLARZELLENMODUL

Title (fr)

CELLULE SOLAIRE ET MODULE CELLULE SOLAIRE

Publication

**EP 2650923 A1 20131016 (EN)**

Application

**EP 11846590 A 20111201**

Priority

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Abstract (en)

A solar cell wherein: an emitter layer is formed on a light-receiving-surface side of a crystalline silicon substrate, with a dopant of the opposite conductivity type from the silicon substrate added to said emitter layer; a passivation film is formed on the surface of the silicon substrate; and an extraction electrode and a collector electrode are formed. Said extraction electrode extracts photogenerated charge from the silicon substrate, and said collector electrode contacts the extraction electrode at least partially and collects the charge collected at the extraction electrode. The extraction electrode contains a first electrode that consists of a sintered conductive paste containing a dopant that makes silicon conductive. Said first electrode, at least, is formed so as to pass through the abovementioned passivation layer. The collection electrode contains a second electrode that has a higher conductivity than the aforementioned first electrode. This invention reduces contact-resistance losses between the silicon and the electrodes, resistance losses due to electrode resistance, and optical and electrical losses in the emitter layer, thereby greatly improving the characteristics of the solar cell.

IPC 8 full level

**H01L 31/04** (2006.01)

CPC (source: EP KR US)

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